

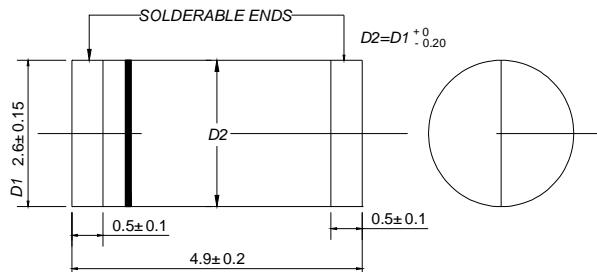


SM5817 THRU SM5819

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIERS

VOLTAGE RANGE: 20 --- 40 VCURRENT: 1.0 A

DO-213AB



Dimensions in millimeters

FEATURES

- ◇ Metal-Semiconductor junction with guard ring
- ◇ Epitaxial construction
- ◇ Low forward voltage drop, low switching losses
- ◇ High surge capability
- ◇ For use in low voltage, high frequency inverters free wheeling, and polarity protection applications
- ◇ The plastic material carries U/L recognition 94V-0

MECHANICAL DATA

- ◇ Case: JEDEC DO-213AB, molded plastic
- ◇ Terminals: Solderable per MIL-STD-202, method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.0046 ounces, 0.116 grams
- ◇ Mounting position: Any

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

MDD Catalog Number		SM5817	SM5818	SM5819	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	20	30	40	V
Maximum RMS voltage	V_{RMS}	14	21	28	V
Maximum DC blocking voltage	V_{DC}	20	30	40	V
Maximum average forward rectified current @ $T_A=90^\circ\text{C}$	$I_{F(AV)}$	1.0			
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load	I_{FSM}	25			
Maximum instantaneous forward voltage @ 1.0A (Note 1) @ 3.0A	V_F	0.45 0.75	0.55 0.875	0.60 0.90	V
Maximum reverse current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=100^\circ\text{C}$	I_R	1.0 10.0			
Typical junction capacitance (Note 2)	C_J	110			
Typical thermal resistance (Note 3)	$R_{\theta JA}$	80			
Operating junction temperature range	T_J	-55 ---- +150			
Storage temperature range	T_{STG}	-55 ---- +150			

NOTE: 1. Pulse test : 300 μs pulse width, 1% duty cycle.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance junction to ambient, vertical PC board mounting, 0.5" (12.7mm) lead length.

MDD ELECTRONIC

RATINGS AND CHARACTERISTIC CURVES SM5817--SM5819

FIG.1 – FORWARD DERATING CURVE

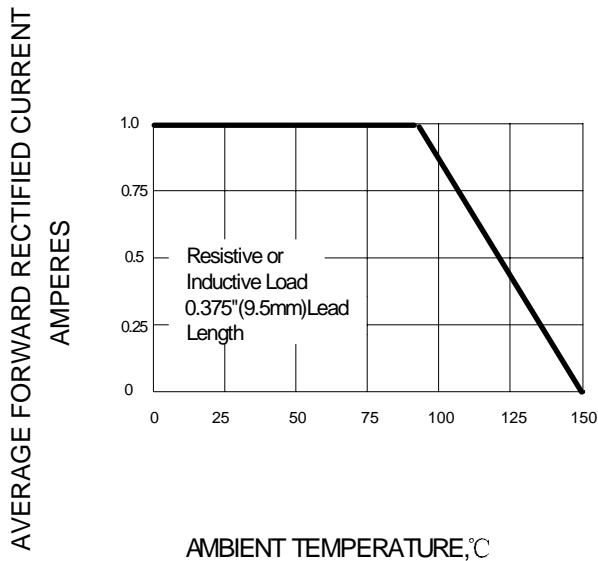


FIG.2 – PEAK FORWARD SURGE CURRENT

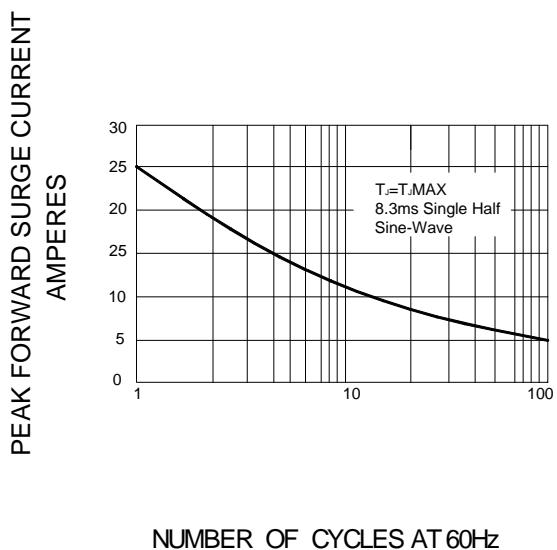


FIG.3 – TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

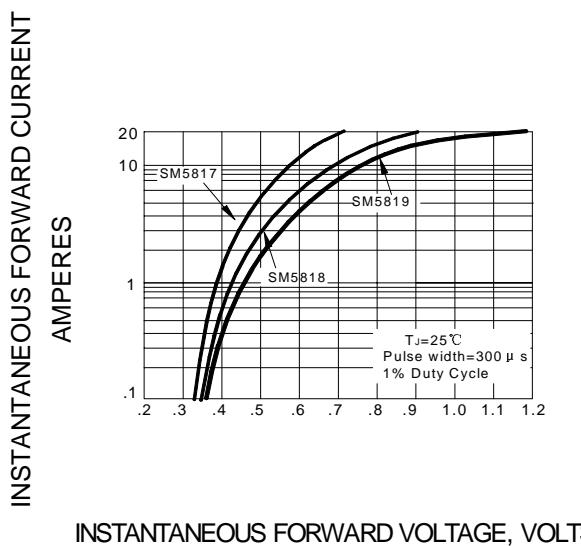
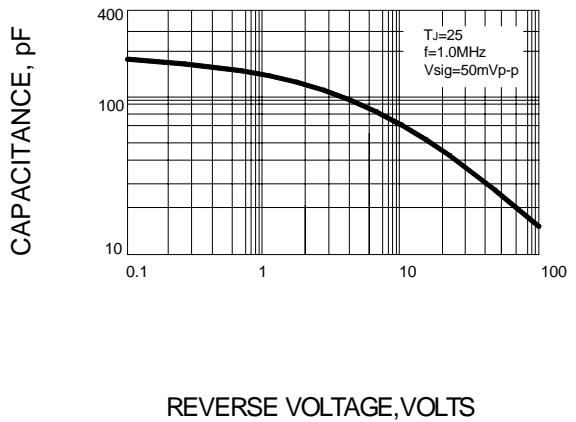


FIG.4 – TYPICAL JUNCTION CAPACITANCE



INSTANTANEOUS FORWARD VOLTAGE, VOLTS

REVERSE VOLTAGE, VOLTS

MDD ELECTRONIC